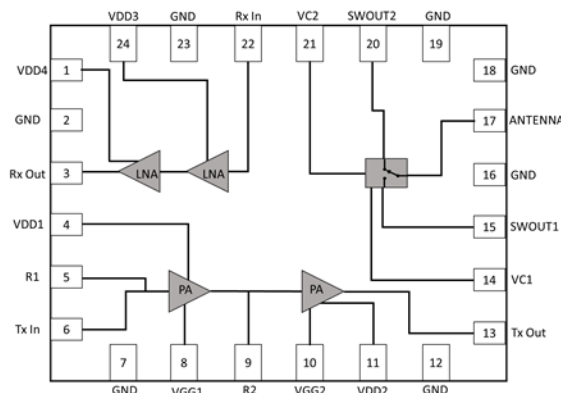


Features:

- RF Frequency: 2-6 GHz
- Tx Gain : 23.2 dB
- Rx Gain : 27.2 dB
- Rx Noise Figure : 1 dB
- Tx Output P1dB (OP1dB) : 23 dBm
- Rx Output P1dB (OP1dB) : 11.8 dBm
- Tx Current = 355.1 mA , Rx Current = 48.4 mA
- Tx Voltage = 4 / -0.5 V , Rx Voltage = 4 / -0.5 V
- 0.1um GaAs pHEMT Technology
- Die Size:1.2 mm*1.45 mm

Functional Block Diagram



Description:

RFFEM06S is a Front-End Module that operates from 2 – 6 GHz and it is used to drive the high-power amplifier. The amplifier provides Tx Gain = 23.2 dB, and Rx Gain = 27.2 dB the input and output are matched to 50 ohms with off-chip DC blocking capacitors.

The device is specifically designed for 2-6 GHz frequency in Bluetooth, Radar Systems, WiFi, IoT, and SATCOM Applications.

The Technology used to design Front End Module is 0.1um GaAs pHEMT Process.

Applications:

- Bluetooth
- Radar Systems
- SATCOM
- IoT
- Wi-Fi

Pin Configuration

Pin No.	Pin Name	Description
1,4,11,24	VDD	Drain Voltage
2,7,12,16,18,19,23	GND	Ground
3	Rx Out	Receiver Output
5,9	R	
6	Tx In	Transmitter Input
8,10	VGG	Gate Voltage
13	Tx Out	Transmitter Output
14,21	VC	Voltage Control
15,20	SWOUT	Switch Output
17	ANTENNA	
22	Rx In	Receiver Input

Deliverables:

- Sample Ready Die
- Product Datasheet

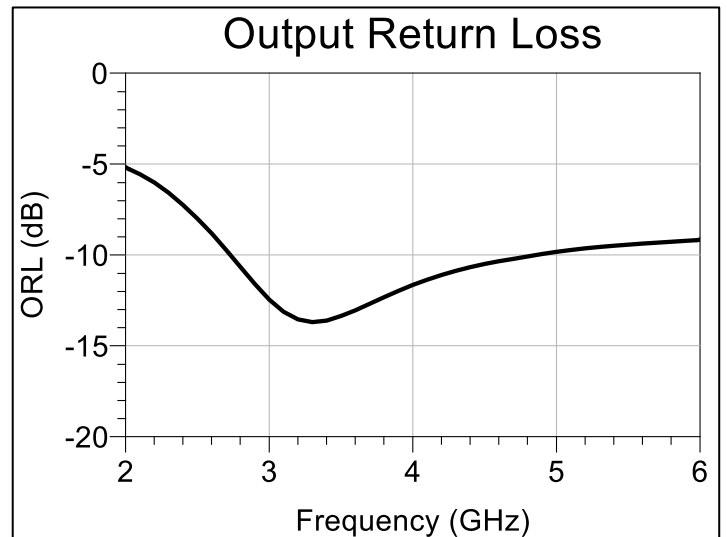
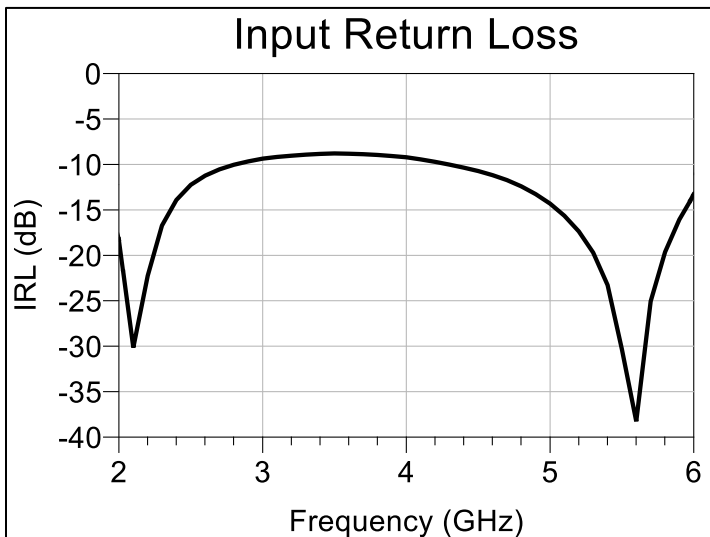
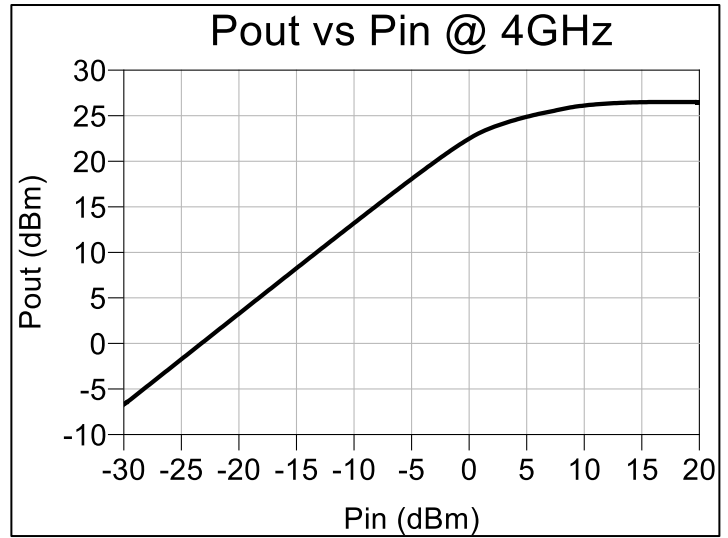
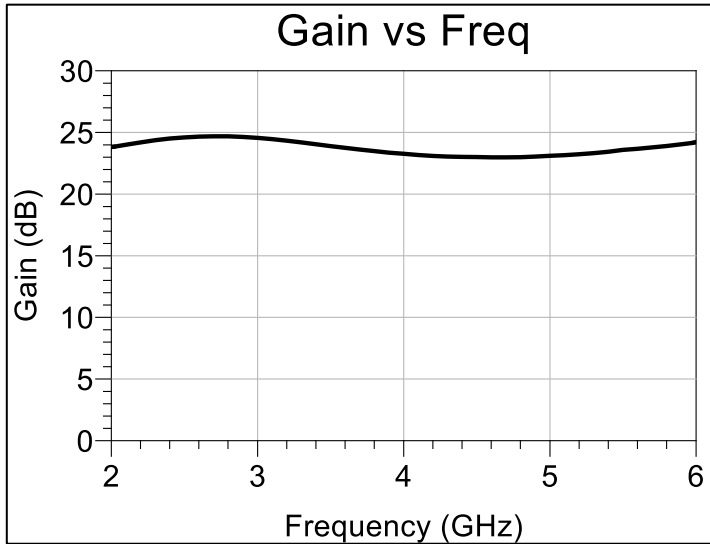
RFIC confidential property not to be copied or disclosed without prior authorization.

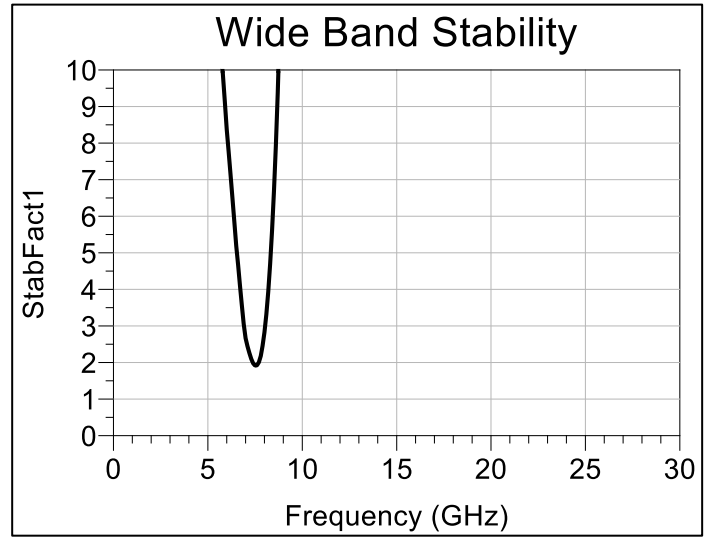
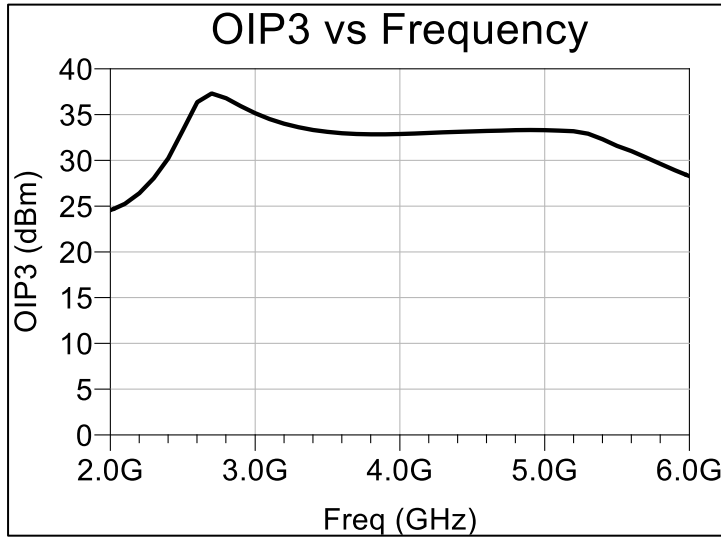
Electrical Specification:

Freq= 2 - 6 GHz, Tx Voltage = 4 / -0.5 V, Rx Voltage = 4 / -0.5 V, Tx Current =355.1 mA, Rx Current =48.4 mA, Zo=50 Ω

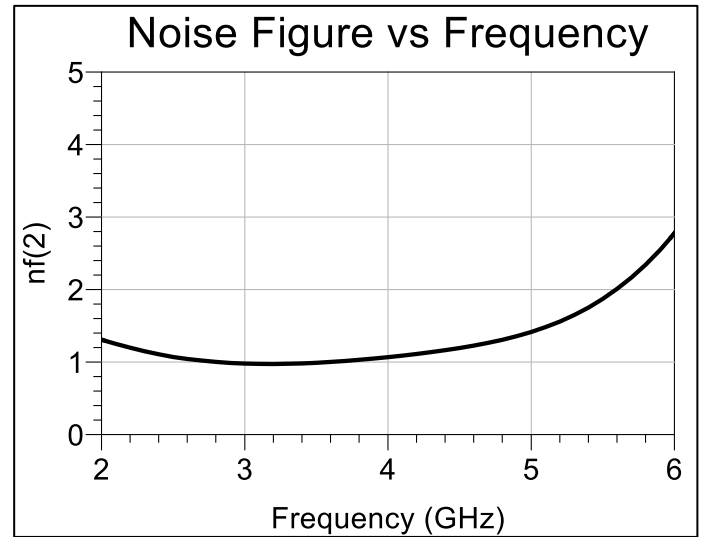
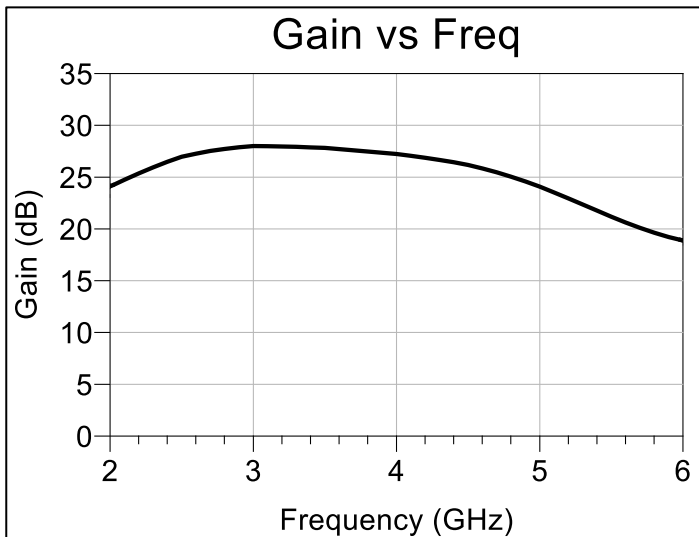
Parameters	Test Condition	Units	TX	RX
Gain	2 GHz	dB	23.7	24
	4 GHz		23.2	27.2
	6 GHz		24	18.8
Output P1 dB	2 GHz	dBm	-	-
	4 GHz		23	11.8
	6 GHz		-	-
OIP3 Pin= 1 dBm Δf = 50MHz	2 GHz	dBm	-	-
	4 GHz		32.8	22.8
	6 GHz		-	-
Noise Figure	2 GHz	dB	-	1.3
	4 GHz		-	1
	6 GHz		-	2.7
Input Return Loss	2 GHz	dB	18.2	3.4
	4 GHz		9.2	5.5
	6 GHz		13.3	2.9
Output Return Loss	2 GHz	dB	5.19	16
	4 GHz		11.65	13
	6 GHz		9.17	7.2
Operating Bias Conditions				
Drain Current (Id)	-	mA	355.1 / 48.4	
Drain Voltage (VDD)	-	V	Rx = 4 Tx = 4	
Gate Voltage (VGG)	-	V	Rx = -0.5, Tx = -0.5	

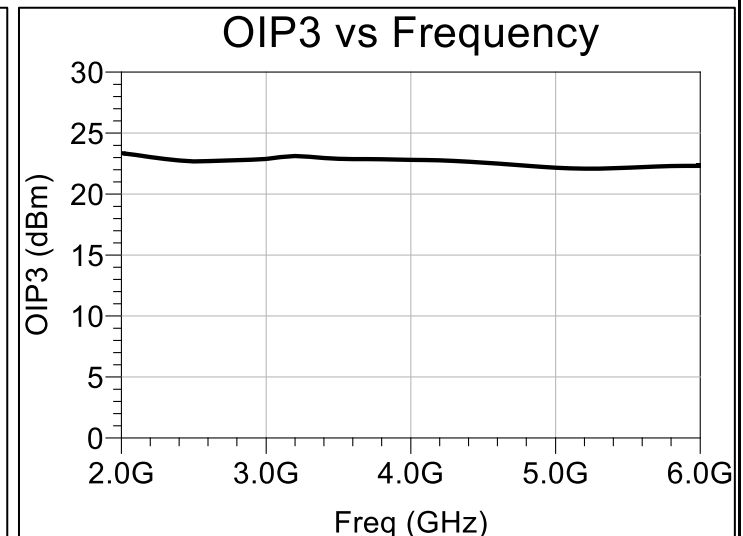
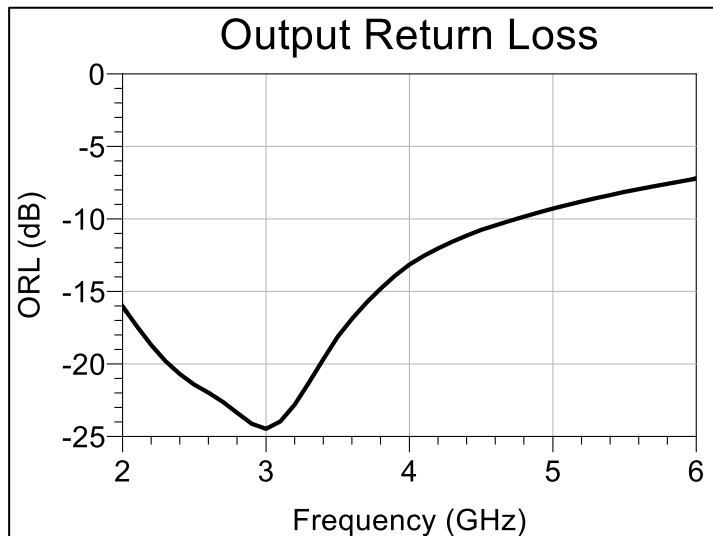
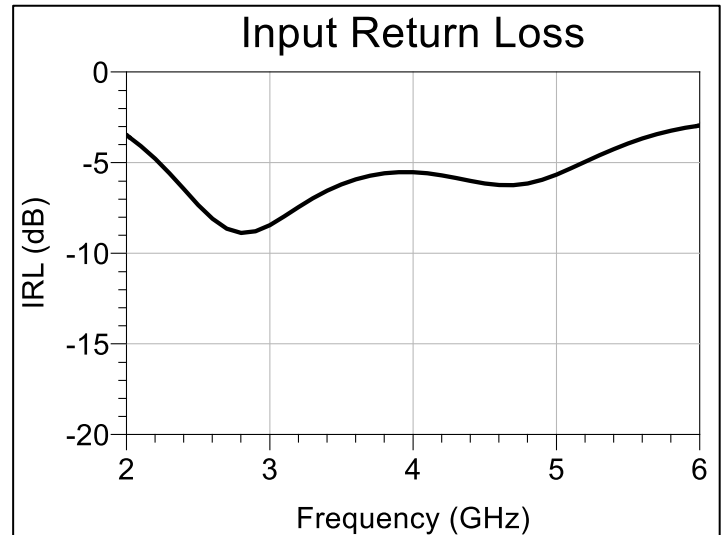
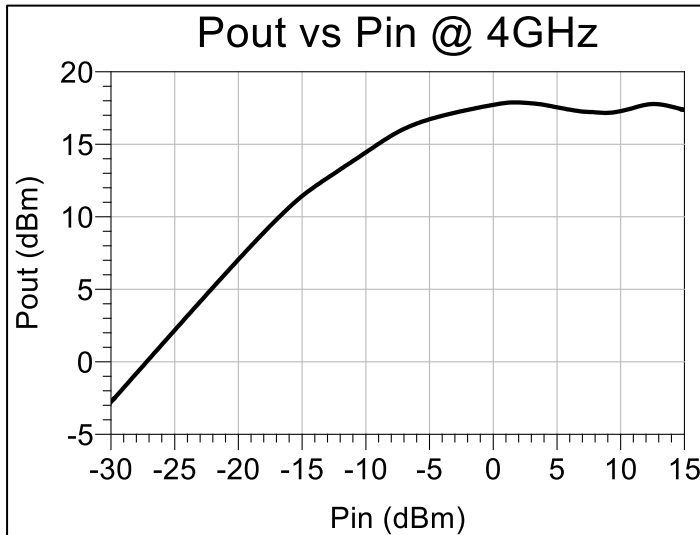
Typical Performance Curves (Tx):

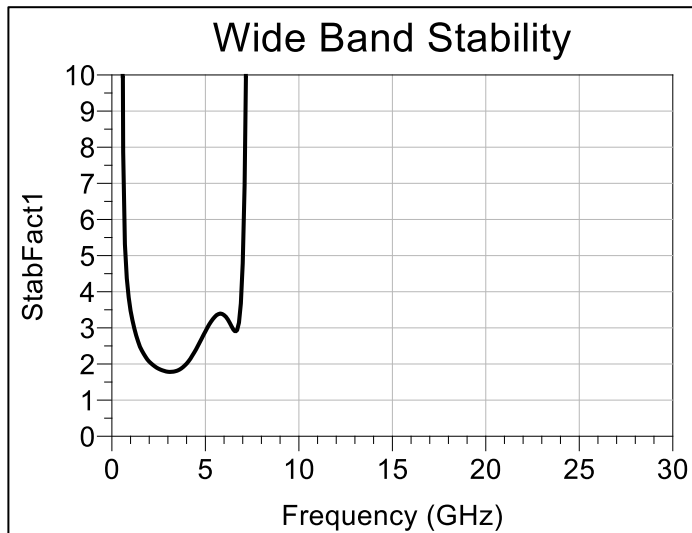




Typical Performance Curves (Rx):







Disclaimer:

Information in this document is provided in connection with RFIC Solutions Inc. products. These materials are provided by RFIC Solutions Inc. as a service to its customers and may be used for informational purposes only. Except as provided in RFIC Solutions Inc. Terms and Conditions of Sale for such products or in any separate agreement related to this document, RFIC Solutions Inc. assumes no liability whatsoever. RFIC Solutions Inc. assumes no responsibility for errors or omissions in these materials. RFIC Solutions Inc. may make changes to specifications and product descriptions at any time, without notice. RFIC Solutions Inc. makes no commitment to update the information and shall have no responsibility whatsoever for conflicts or incompatibilities arising from future changes to its specifications and product descriptions. No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document.

Contact information

For the latest specifications, additional product information:

Web: www.rficsolutions.com

Email: smoghe@rficsolutions.com

Tel: (+91) 840 356 8957, (+91)9022078131, (+91)8485841789

RFIC confidential property not to be copied or disclosed without prior authorization.